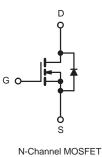


N-Channel 200 V (D-S) MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	R _{DS(on)} (Ω) I _D (A				
200	0.010 at V _{GS} = 10 V	160			

TO-220 Pin Configuration





Top View

FEATURES

- DT-Trench Power MOSFET
- 175 °C Junction Temperature
- PWM Optimized
- 100 % R_g Tested
- Compliant to RoHS Directive 2002/95/EC

APPLICATIONS

Primary Side Switch

ABSOLUTE MAXIMUM RATINGS ($T_A = 2$	25 °C, unless other	wise noted)		
Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V _{DS}	200	V
Gate-Source Voltage	V _{GS}	± 20	V	
Continuous Drain Current (T _{.1} = 175 °C) ^b	T _C = 25 °C	- I _D	160	
Continuous Drain Current $(T_J = 175^{\circ}C)^2$	T _C = 100 °C		100	
Pulsed Drain Current	I _{DM}	430	А	
Continuous Source Current (Diode Conduction)	۱ _S	160		
Avalanche Current	I _{AS}	88		
Single Pulse Avalanche Energy	L = 0.1 mH	E _{AS}	386	mJ
Maximum Power Discipation	T _C = 25 °C	PD	416 ^b	w
Maximum Power Dissipation	T _C = 100 °C	- U	131 ^a	VV
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 175	°C

THERMAL RESISTANCE RATINGS								
Parameter	Symbol	Typical	Maximum	Unit				
hunstion to Ambienta	$t \le 10 \text{ s}$	R _{thJA}		15	°C/W			
Junction-to-Ambient ^a	Steady State	1 thJA		46				
Junction-to-Case (Drain)	R _{thJC}		1.0					

Notes:

a. Surface mounted on 1" x 1" FR4 board.

b. See SOA curve for voltage derating.



Parameter	Symbol	Test Conditions	Min.	Typ. ^a	Max.	Unit	
Static	•	·		•			
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, \text{ I}_{D} = 250 \mu\text{A}$	200			V	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \ \mu A$	2		5	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
		V _{DS} = 160 V, V _{GS} = 0 V			1		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 160 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 125 \text{ °C}$			50	μA	
		$V_{DS} = 160 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 175 ^{\circ}\text{C}$			250		
On-State Drain Current ^b	I _{D(on)}	V _{DS} = 5 V, V _{GS} = 10 V	160			А	
		V _{GS} = 10 V, I _D = 20 A		0.01	0.014	Ω	
Drain Course On Chata Daviston ash	Real	V _{GS} = 10 V, I _D = 20 A, T _J = 125 °C			0.015		
Drain-Source On-State Resistance ^b	R _{DS(on)}	V_{GS} = 10 V, I _D = 20 A, T _J = 175 °C			0.019		
		$V_{GS} = 6 \text{ V}, \text{ I}_{D} = 20 \text{ A}$ 0.015 (0				1	
Forward Transconductance ^b	9 _{fs}	V _{DS} = 15 V, I _D = 20 A		56		S	
Dynamic ^a							
Input Capacitance	C _{iss}			9800			
Output Capacitance	C _{oss}	V_{GS} = 0 V, V_{DS} = 100 V, F = 1 MHz		1060		pF	
Reverse Transfer Capacitance	C _{rss}			560			
Total Gate Charge ^c	Qg			44			
Gate-Source Charge ^c	Q _{gs}	V_{DS} = 100 V, V_{GS} = 10 V, I_{D} = 20 A		18		nC	
Gate-Drain Charge ^c	Q _{gd}			12			
Gate Resistance	Rg		0.5		2.9	Ω	
Turn-On Delay Time ^c	t _{d(on)}			19			
Rise Time ^c	tr	V_{DD} = 100 V, R _L = 5.2 Ω		25		ns	
Turn-Off Delay Time ^c	t _{d(off)}	$\rm I_D \cong 20$ A, $\rm V_{GEN}$ = 10 V, $\rm R_g$ = 2.5 Ω		30			
Fall Time ^c	Fime ^c t _f			10]	
Source-Drain Diode Ratings and Char	acteristics (1	Γ _C = 25 °C)					
Pulsed Current	I _{SM}				430	А	
Diode Forward Voltage ^b	V _{SD}	I _F = 20 A, V _{GS} = 0 V		0.9	1.5	V	
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 19 A, dl/dt = 100 A/μs		80		ns	

Notes:

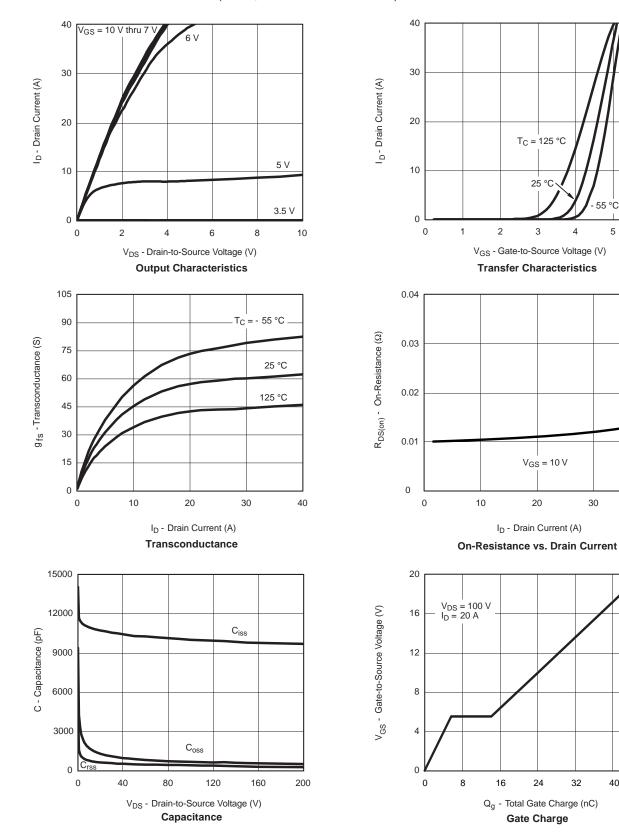
a. Guaranteed by design, not subject to production testing.

b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %. c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



55 °C



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

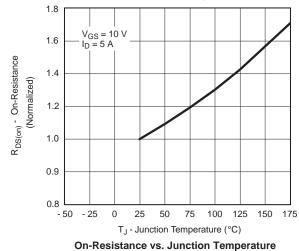


T_J = 25 °C

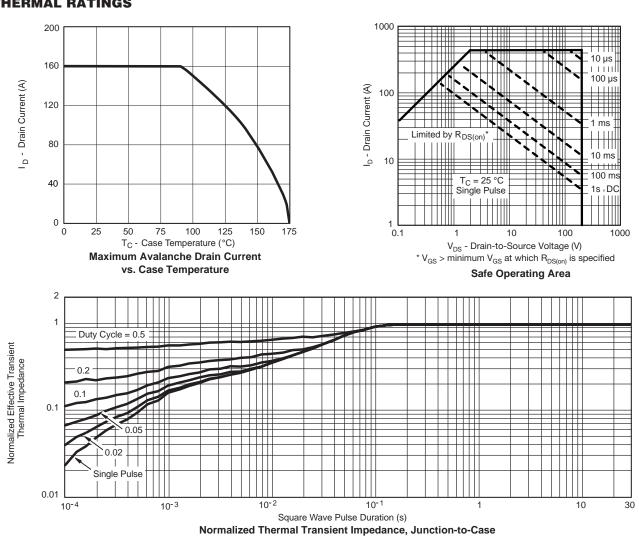
0.9

1.2

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



THERMAL RATINGS



100

10

1

0

0.3

T_J = 150 °C

0.6

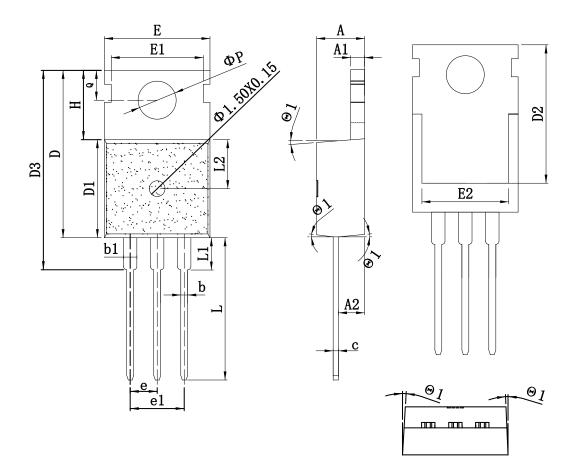
V_{SD} - Source-to-Drain Voltage (V)

Source-Drain Diode Forward Voltage

I_S - Source Current (A)



TO-220_3L-A PACKAGE OUTLINE

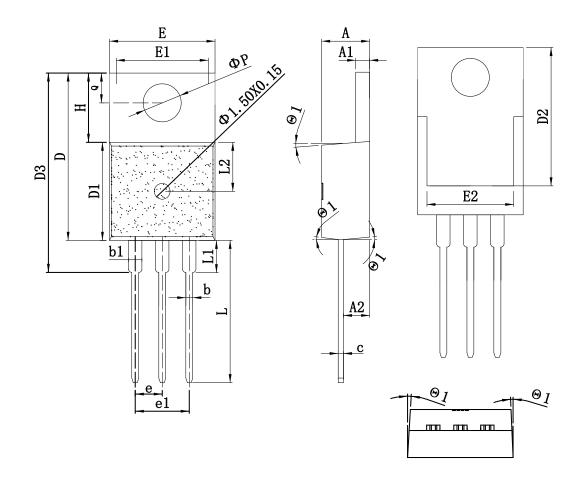


COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

SYMBOL		mm			mm			
SIMBOL	MIN	TYP	MAX	SYMBOL	MIN	TYP	MAX	
А	4.15	4.50	4.80	E1	8.25	8.70	9.15	
A1	1.15	1.30	1.50	E2	7.20	8.00	8.80	
A2	2.10	2.40	2.65	e	2.38	2.54	2.74	
b	0.65	0.80	1.00	e1	5.08REF			
b1	1.10	1.33	1.80	Н	6.20	6.50	6.90	
с	0.35	0.50	0.65	L	12.75	13.28	13.70	
D	14.25	15.75	16.15	L1	-	-	3.50	
D1	8.70	9.20	9.60	L2	2.30	4.65	7.00	
D2	12.30	13.10	13.85	φP	3.40	3.65	3.85	
D3	16.20	18.80	20.60	Q	2.50	2.80	3.00	
Е	8.68	10.02	11.00	θ	2°	-	7°	



TO-220_3L-B PACKAGE OUTLINE



COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

SYMBOL	mm			SYMBOL	mm			
SIMBOL	MIN	TYP	MAX	SIMBOL	MIN	TYP	MAX	
А	4.15	4.50	4.80	E1	8.25	8.70	9.15	
A1	1.15	1.30	1.50	E2	7.20	8.00	8.80	
A2	2.10	2.40	2.65	e	2.38	2.54	2.74	
b	0.65	0.80	1.00	e1	5.08REF			
b1	1.10	1.33	1.80	Н	6.20	6.50	6.90	
с	0.35	0.50	0.65	L	12.75	13.28	13.70	
D	14.25	15.75	16.15	L1	-	-	3.50	
D1	8.70	9.20	9.60	L2	2.30	4.65	7.00	
D2	12.30	13.10	13.85	φP	3.40	3.65	3.85	
D3	16.20	18.80	20.60	Q	2.50	2.80	3.00	
Е	8.68	10.02	11.00	θ	2°	-	7°	

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